Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Glass

Overall Length:

4.250 millimeters

Terminal Length:

2.600 millimeters

Overall Width:

1.600 millimeters

End Application:

General purpose electronic test equipment

Mounting Facility Quantity:

3

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

25.0 breakdown voltage, collector to emitter, sustained and 25.0 breakdown voltage, collector-to-base, emitter open

Current Rating Per Characteristic:

0.70 milliamperes source cutoff current

Power Rating Per Characteristic:

2.0 watts small-signal output power, common-base preset

Maximum Operating Tempurature Per Measurement Point:

-55.0 degrees celsius case and 150.0 degrees celsius case

Special Features:

Single hf power si npn bjt

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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